

SKET 330



SEMIPACK[®] 4

Thyristor Modules

SKET 330

Features

- Heat transfer through aluminium nitride ceramic isolated metal baseplate
- Precious metal pressure contacts for high reliability
- Thyristor with amplifying gate
- UL recognized, file no. E 63 532

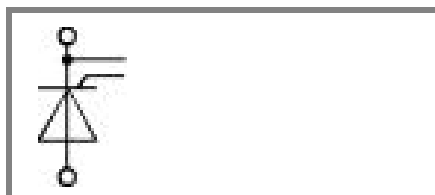
Typical Applications*

- DC motor control (e. g. for machine tools)
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

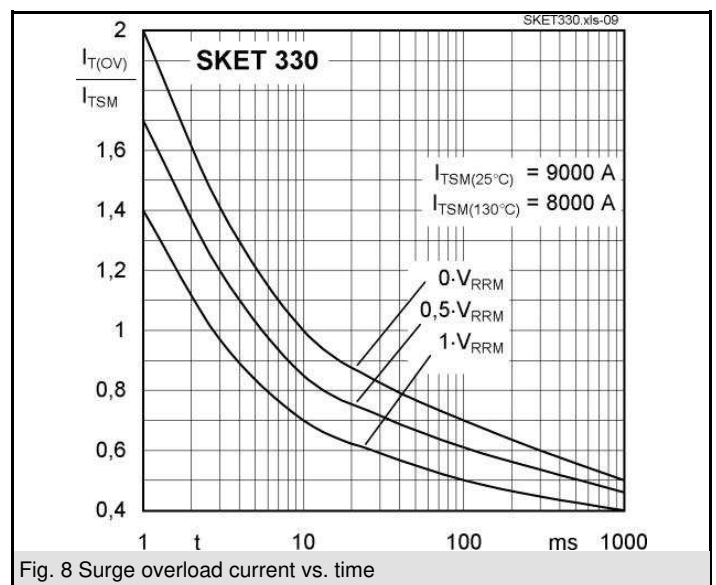
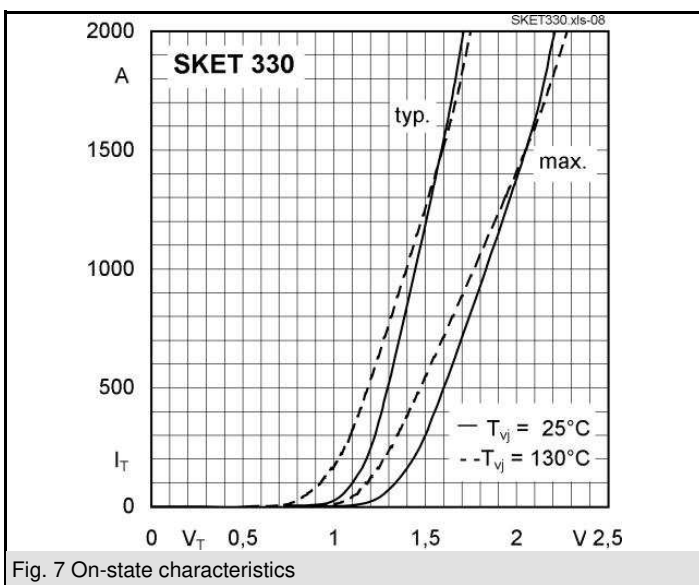
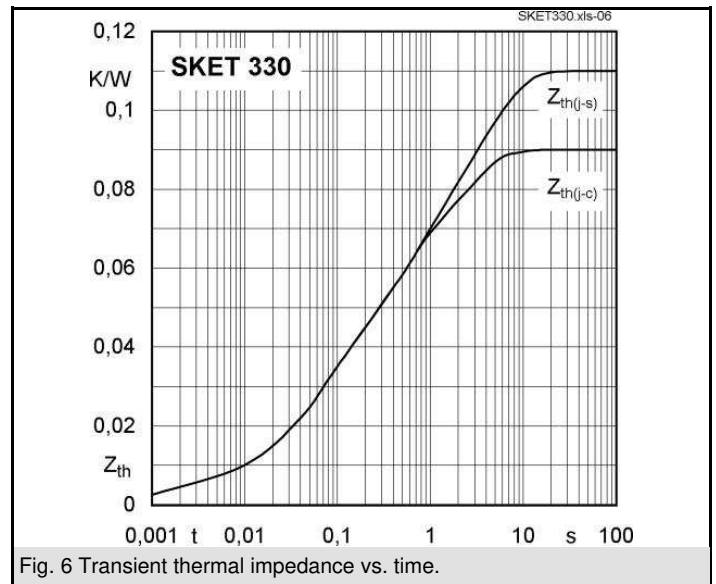
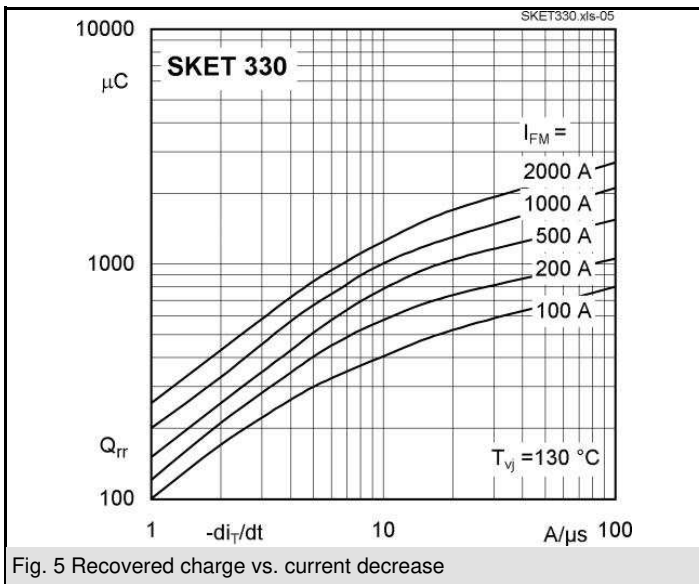
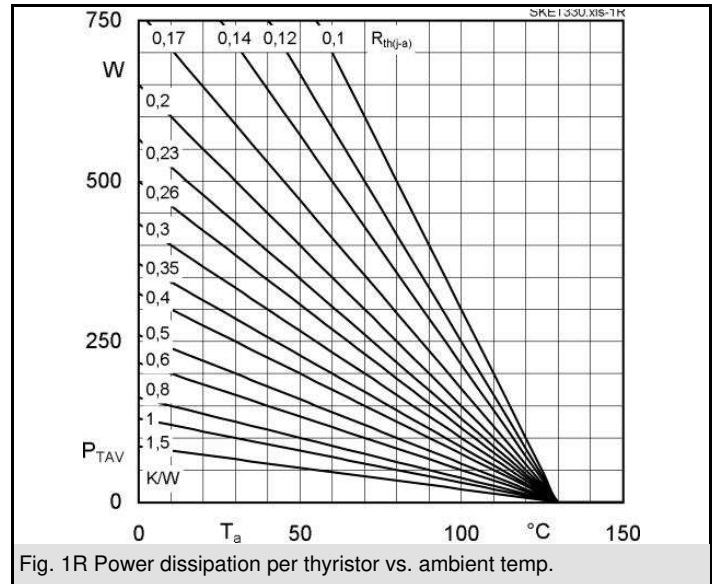
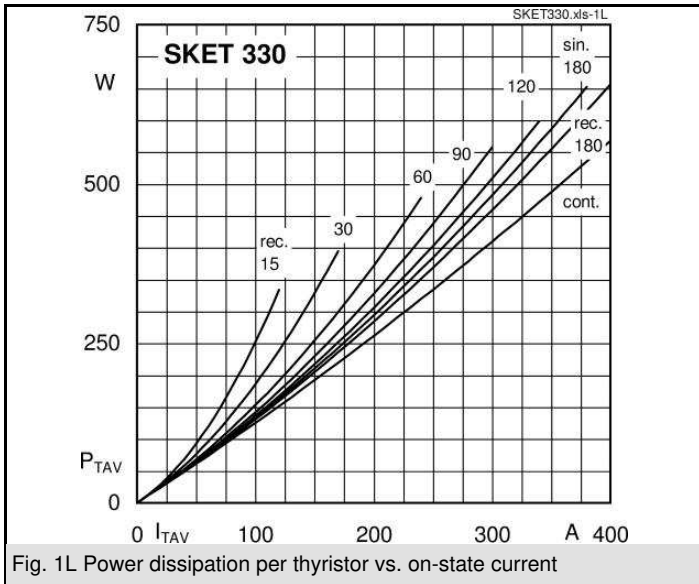
1) See the assembly instructions

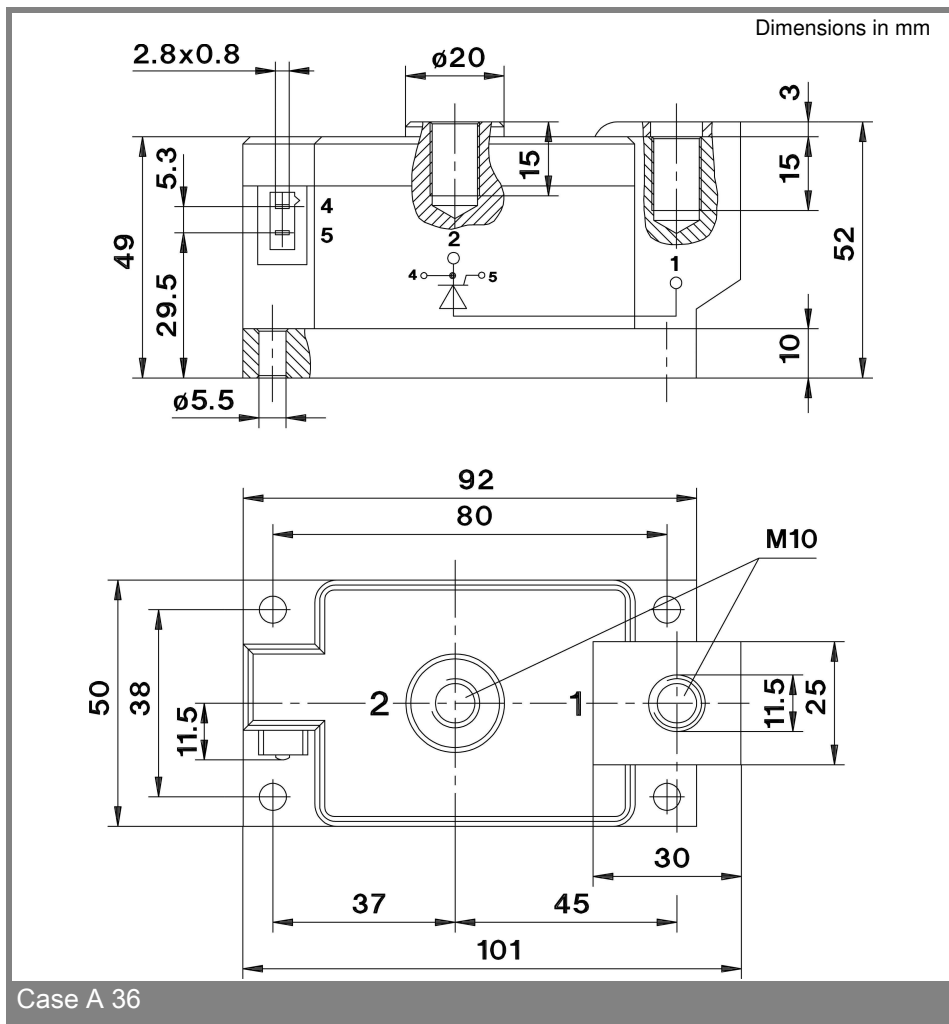
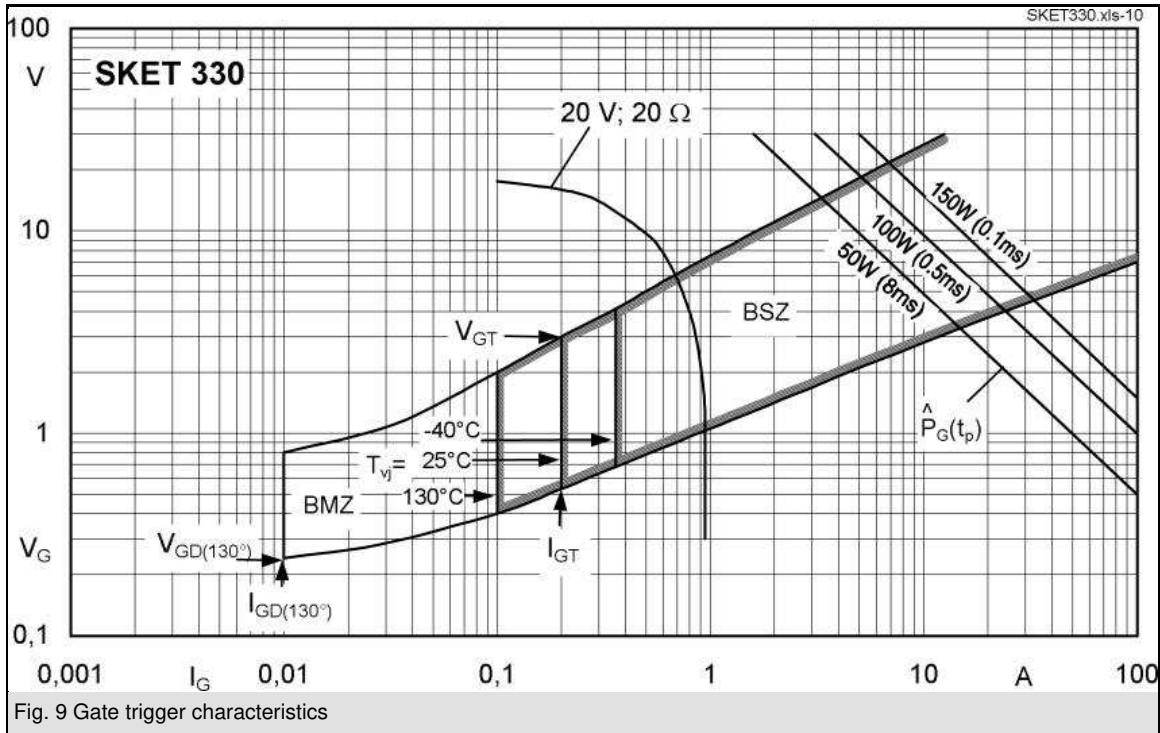
V_{RSM} V	V_{RRM}, V_{DRM} V	$I_{TRMS} = 600$ A (maximum value for continuous operation) $I_{TAV} = 330$ A (sin. 180; $T_c = 78$ °C)	
900	800	SKET 330/08E	
1300	1200	SKET 330/12E	
1500	1400	SKET 330/14E	
1700	1600	SKET 330/16E	
1900	1800	SKET 330/18E	
2100	2000	SKET 330/20E	
2300	2200	SKET 330/22E	

Symbol	Conditions	Values	Units
I_{TAV}	sin. 180; $T_c = 85$ (100) °C;	295 (210)	A
I_D	P16/300F; $T_a = 35$ °C; B2 / B6	530 / 665	A
I_{RMS}	P16/400F; $T_a = 35$ °C; W1 / W3	685 / 3 * 550	A
I_{TSM}	$T_{vj} = 25$ °C; 10 ms	9000	A
	$T_{vj} = 130$ °C; 10 ms	8000	A
i^2t	$T_{vj} = 25$ °C; 8,3 ... 10 ms	405000	A ² s
	$T_{vj} = 130$ °C; 8,3 ... 10 ms	320000	A ² s
V_T	$T_{vj} = 25$ °C; $I_T = 1500$ A	max. 2,05	V
$V_{T(TO)}$	$T_{vj} = 130$ °C	max. 1,2	V
r_T	$T_{vj} = 130$ °C	max. 0,55	mΩ
I_{DD}, I_{RD}	$T_{vj} = 130$ °C; $V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$	max. 200	mA
t_{gd}	$T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs	1	μs
t_{gr}	$V_D = 0,67 * V_{DRM}$	2	μs
$(di/dt)_{cr}$	$T_{vj} = 130$ °C	max. 125	A/μs
$(dv/dt)_{cr}$	$T_{vj} = 130$ °C	max. 1000	V/μs
t_q	$T_{vj} = 130$ °C,	150 ... 200	μs
I_H	$T_{vj} = 25$ °C; typ. / max.	150 / 500	mA
I_L	$T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max.	500 / 2000	mA
V_{GT}	$T_{vj} = 25$ °C; d.c.	min. 3	V
I_{GT}	$T_{vj} = 25$ °C; d.c.	min. 200	mA
V_{GD}	$T_{vj} = 130$ °C; d.c.	max. 0,25	V
I_{GD}	$T_{vj} = 130$ °C; d.c.	max. 10	mA
$R_{th(j-c)}$	cont.	0,09	K/W
	sin. 180	0,095	K/W
	rec. 120	0,11	K/W
$R_{th(c-s)}$		0,02	K/W
T_{vj}		- 40 ... + 130	°C
T_{stg}		- 40 ... + 130	°C
V_{isol}	a. c. 50 Hz; r.m.s.; 1s / 1 min.	3600 / 3000	V~
M_s	to heatsink	5 ± 15 % ¹⁾	Nm
M_t	to terminal	17 ± 15 %	Nm
a		5 * 9,81	m/s ²
m	approx.	940	g
Case		A 36	



SKET





* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON

ECTHER DIODE THYRISTOR MODULE

products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our staff.